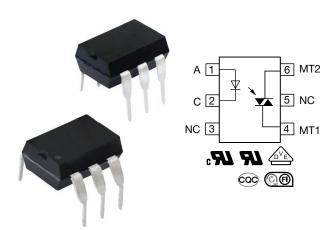


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Vishay Semiconductors

Optocoupler, Phototriac Output, Non-Zero Crossing, 400 V_{DRM}



DESCRIPTION

The K3020P, K3020PG series consists of a phototriac optically coupled to a gallium arsenide infrared-emitting diode in a 6-lead plastic dual inline package.

The non-zero crossing functionality enables full wave control. Featuring galvanic and electrical noise isolation, the output is able to directly switch AC loads or drive medium to high power TRIACs.

FEATURES

- 400 V blocking voltage
- · Wide range of trigger current
- 100 mA_{RMS} on-state current
- Wide temperature range -55 °C to +100 °C
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912





RoHS COMPLIANT

APPLICATIONS

- Power TRIAC driver
- · Isolated AC load switch
- Air condition
- Heaters
- · White goods
- · Industrial controls
- Office equipment

AGENCY APPROVALS

- UL
- cUL
- DIN EN 60747-5-5 (VDE 0884-5)
- CQC: GB4943-1-2011
- CQC: GB8898-2011
- FIMKO

ORDERING INFORMATION						
K 3 0	TRI	X P GGER PACKA ENT BIN OPTIC	GE GE	P-6 G leadform		
AGENCY CERTIFIED / PACKAGE	TRIGGER CURRENT, I _{FT}					
VDE, cUL, BSI	5 mA	10 mA	15 mA	30 mA		
DIP-6	K3023P	K3022P	K3021P	K3020P		
DIP-6, 400 mil	K3023PG	K3022PG	K3021PG	K3020PG		

Note

• Additional options may be possible, please contact sales office.

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ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT		
INPUT						
Reverse voltage		V_R	5	V		
Forward current		I _F	80	mA		
Surge current	P.W. < 10 μs	I _{FSM}	3	Α		
Power dissipation		P _{diss}	100	mW		
Junction temperature		Tj	125	°C		
OUTPUT						
Peak off-state voltage		V_{DRM}	400	V		
On-state RMS current		I _{D(RMS)}	100	mA		
Peak surge current	t _p ≤ 10 ms	I _{FSM}	1.5	Α		
Power dissipation		P _{diss}	300	mW		
Junction temperature		Tj	125	°C		
COUPLER	•					
Total power dissipation		P _{tot}	350	mW		
Storage temperature range		T _{stg}	-55 to +150	°C		
Ambient temperature		T _{amb}	-55 to +100	°C		
Lead soldering temperature	2 mm from case, t < 10 s	T _{sld}	260	°C		

Note

• Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.

ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
INPUT							
Forward voltage	I _F = 50 mA		V _F	-	1.3	1.6	V
Reverse voltage	I _R = 10 μA		V _R	5	-	-	V
Junction capacitance	$V_R = 0 V, f = 1 MHz$		C _j	-	50	-	pF
OUTPUT							
Forward peak off-state voltage (repetitive)	I _{DRM} = 100 nA		V _{DRM} ⁽¹⁾	400	-	-	V
Peak on-state voltage	I _{TM} = 100 mA		V _{TM}	=	1.5	3	V
Critical rate of rise of off-state voltage	$I_F = 0 \text{ A}, V_D = 0.67 V_{DRM}$		dV/dt _{cr}	-	10	-	V/µs
Critical rate of rise of on-state current commutation	$V_D = 30 V_{RMS}, I_D = 15 mA_{RMS}$		dV/dt _{crq}	0.1	0.15	-	V/µs
COUPLER (2)							
Emitting diode trigger current	V_S = 3 V, R_L = 150 Ω	K3020P	I _{FT}	=	15	30	mA
		K3020PG	I _{FT}	-	15	30	mA
		K3021P	I _{FT}	-	8	15	mA
		K3021PG	I _{FT}	-	8	15	mA
		K3022P	I _{FT}	1	5	10	mA
		K3022PG	I _{FT}	1	5	10	mA
		K3023P	I _{FT}	-	3	5	mA
		K3023PG	I _{FT}	-	3	5	mA
Holding current	$I_F = 10 \text{ mA}, V_S \ge 3 \text{ V}$		I _H	-	200	-	μΑ

Notes

- Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering
 evaluation. Typical values are for information only and are not part of the testing requirements.
- (1) Test voltage must be applied within dV/dt ratings.
- (2) IFT is defined as a minimum trigger current.

PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Climatic classification	According to IEC 68 part 1		55 / 100 / 21	
Pollution degree	According to DIN VDE 0109		2	
Comparative tracking index	Insulation group Illa	CTI	175	
Maximum rated withstanding isolation voltage	According to UL1577, t = 1 min	V_{ISO}	4420	V _{RMS}
Tested withstanding isolation voltage	According to UL1577, t = 1 s	V _{ISO}	5300	V _{RMS}
Maximum transient isolation voltage	According to DIN EN 60747-5-5	V_{IOTM}	8000	V _{peak}
Maximum repetitive peak isolation voltage	According to DIN EN 60747-5-5	V _{IORM}	890	V _{peak}
Isolation resistance	V _{IO} = 500 V, T _{amb} = 25 °C	R _{IO}	≥ 10 ¹²	Ω
	V _{IO} = 500 V, T _{amb} = 100 °C	R _{IO}	≥ 10 ¹¹	Ω
Output safety power		P _{SO}	265	mW
Input safety current		I _{SI}	130	mA
Input safety temperature		T _S	150	°C
Creepage distance	DIP-6		≥ 7	mm
Clearance distance	DIF-0		≥ 7	mm
Creepage distance	DIP-6. 400 mil		≥ 8	mm
Clearance distance	DIP-0, 400 IIII		≥ 8	mm
Insulation thickness		DTI	≥ 0.4	mm
Input to output test voltage, method A	V_{IORM} x 1.6 = V_{PR} , 100 % sample test with t_M = 10 s, partial discharge < 5 pC	V_{PR}	1424	V _{peak}

Note

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

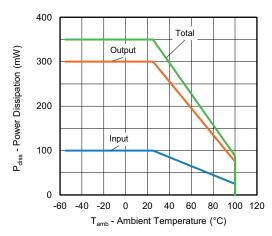


Fig. 1 - Total Power Dissipation vs. Ambient Temperature

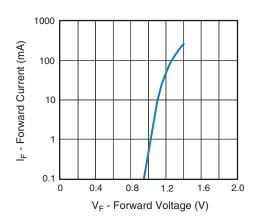


Fig. 2 - Forward Current vs. Forward Voltage

[•] As per IEC 60747-5-5, § 7.4.3.8.2, this optocoupler is suitable for "safe electrical insulation" only within the safety ratings. Compliance with the safety ratings shall be ensured by means of protective circuits.

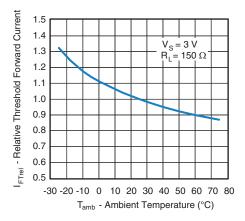


Fig. 3 - Relative Threshold Forward Current vs.
Ambient Temperature

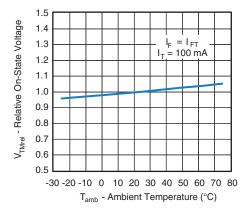


Fig. 4 - Relative On-State vs. Ambient Temperature

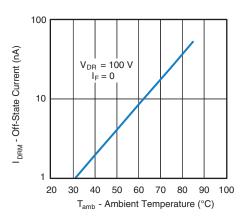


Fig. 5 - Off-State Current vs. Ambient Temperature

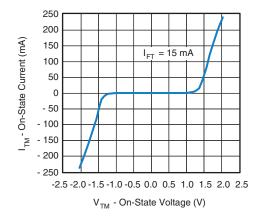
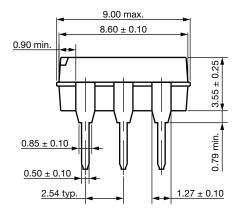
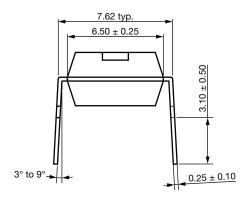


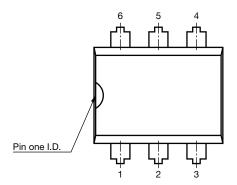
Fig. 6 - On-State Current vs. On-State Voltage

PACKAGE DIMENSIONS (in millimeters)

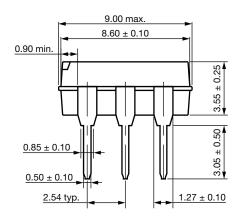
DIP-6

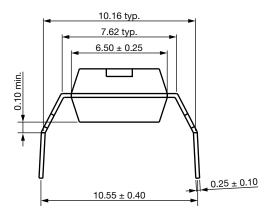


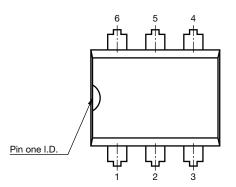




DIP-6, 400 mil







PACKAGE MARKING



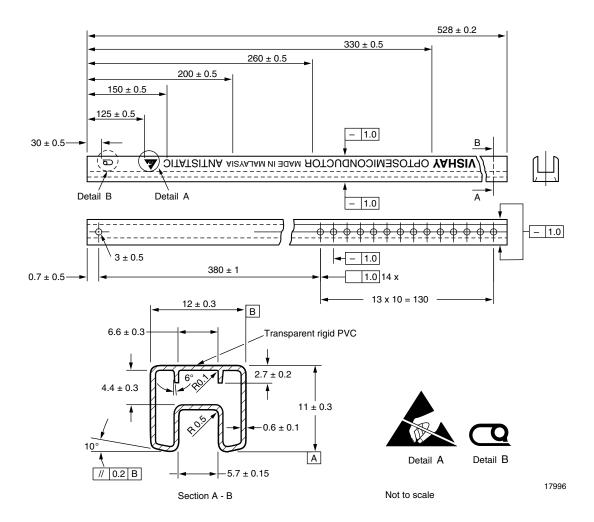
Fig. 7 - Example of K3020P

Notes

- The "G" of the G leadform type is not marked on the body.
- The VDE logo is only marked on ption1 parts.

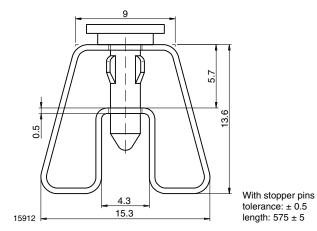
PACKAGING INFORMATION (in millimeters)

DIP-6



DIP-6, 400 mil

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SHIPPING INFORMATION

DEVICES PER TUBS						
TYPE	UNITS/TUBE	TUBES/BOX	UNITS/BOX			
DIP-6	50	40	2000			

SOLDER PROFILES

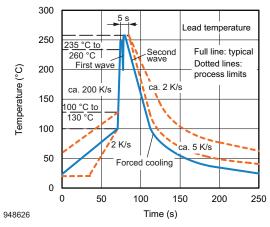


Fig. 8 - Wave Soldering Double Wave Profile According to J-STD-020 for DIP Devices

HANDLING AND STORAGE CONDITIONS

ESD level: HBM class 2 Floor life: unlimited

Conditions: T_{amb} < 30 °C, RH < 85 %

Moisture sensitivity level 1, according to J-STD-020



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